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Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







TOSHIBA

TOSHIBA Photocoupler GaAlAs Ired & Photo-IC

TLP251

Inverter For Air Conditioner **Induction Heating Transistor Inverter** Power MOS FET Gate Drive **IGBT Gate Drive**

The TOSHIBA TLP251 consists of a GaAlAs light emitting diode and a integrated photodetector.

This unit is 8-lead DIP package.

TLP251 is suitable for gate driving circuit of IGBT or power MOS FET. Especially TLP251 is capable of "direct" gate drive of lower power IGBTS. (~15A)

- Input threshold current: IF=5mA(max.)
- Supply current (ICC): 11mA(max.)
- Supply voltage (V_{CC}): 10-35V
- Output current (I_O): ±0.4A(max.)
- Switching time (t_{pLH} / t_{pHL}): $1\mu s(max.)$
- Isolation voltage: 2500Vrms(min.)
- UL recognized: UL1577, file no.E67349
- Option(D4)

VDE Approved: DIN EN60747-5-2/

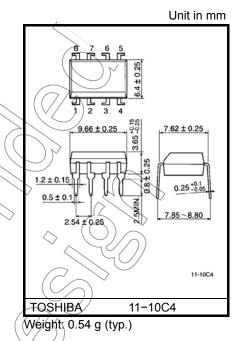
Maximum Operating Insulation Voltage 3890VPK $4000V_{PK}$

Highest Permissible Over Voltage

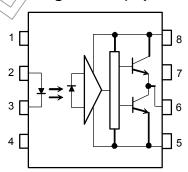
(Note): When a EN60747-5-2 approved type is needed, Please designate "Option(D4)"

Truth Table

		Tr1	Tr2
Input	On	On	Off
LEQ	Off	Off	On
	7/		



Pin Configuration (top view)

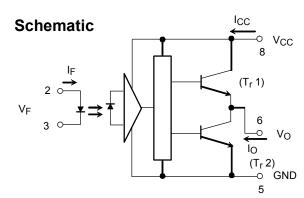


5 : GND 1: N.C.

6 : V_O (Output) 2: Anode

3: Cathode 7: N.C.

8 : V_{CC} 4: N.C.



A 0.1µF bypass capcitor must be connected between pin 8 and 5(see Note 5).

Absolute Maximum Ratings (Ta = 25°C)

Characteristic			Symbol	Rating	Unit	
Forward current			I _F	20	mA	
	Forward current derating (Ta ≥ 70°C)		ΔI _F / ΔTa	- 0.36	mA / °C	
LED	Peak transient forward current (Note 1)		I _{FPT}	1	Α (
	Reverse voltage	Reverse voltage			V	
	Junction temperature		Tj	125	(°C/<	
	"H" peak output current (P _W ≤ 2.0μs, f ≤ 15kHz)	I _{OPH}	- 0.4		/	
	"L" peak output current	(Note 2)				
	C peak output current (P _W ≤ 2.0μs, f ≤ 15kHz)	(Note 2)	I _{OPL}	0.4	A	
Detector	Output voltage	(Ta ≤ 70°C) (Ta = 85°C)	Vo	35	V	
	Supply voltage	(Ta ≤ 70°C) (Ta = 85°C)	Vcc	35 24		
	Output voltage derating (Ta ≥ 70°C)		ΔV _O / ΔΤα	-0.73	V+°C	
	Supply voltage derating (Ta ≥ 70°C)		ΔV _{CC} / ΔΤα	-0.73) v / °C	
	Junction temperature		Tj	125	°C	
Operating frequency (Note 3)			f	25	kHz	
Operating temperature range			Topr	-20~85	°C	
Storage temperature range			Tstg	55~125	°C	
Lead soldering temperature(10s)			Vsøl	260	°C	
	ion voltage (AC, 1min., 60%)	BVS	2500	Vrms		

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Rease design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

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- Note 1: Pulse width P_W ≤ 1µs, 300pps
- Note 2: Expornential waveform
- Note 3: Expornential waveform, $I_{OPH} \le -0.25A(\le 2.0\mu s)$, $I_{OPL} \le +0.25A(\le 2.0\mu s)$
- Note 4: Device considerd a two terminal device: Pins 1, 2, 3 and 4 shorted together, and pins 5, 6, 7 and 8 shorted together.
- Note 5: A ceramic capacitor(0.1µF)should be connected from pin 8 to pin 5 to stabilize the operation of the high gain linear ampifier. Failure to provide the bypassing may impair the swiching property. The total lead length between capacitor and coupler should not exceed 1cm.

Recommended Operating Conditions

Characteristic		Symbol	Min.	Тур.	Max.		Unit
Input current, on	(Note6)	I _{F(ON)}	7	8	10		mA
Input voltage, off		V _{F(OFF)}	0	_	0.8		V
Supply voltage		V _{CC}	10	_	30	20	⟨v
Peak output current		I _{OPH} / I _{OPL}	_	_	±0.1		A
Operating temperature		T _{opr}	-20	25	70	85	,c

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Note 6: Input signal rise time(fall time)<0.5μs.

Electrical Characteristics (Ta = -20~70°C, unless otherwise specified)

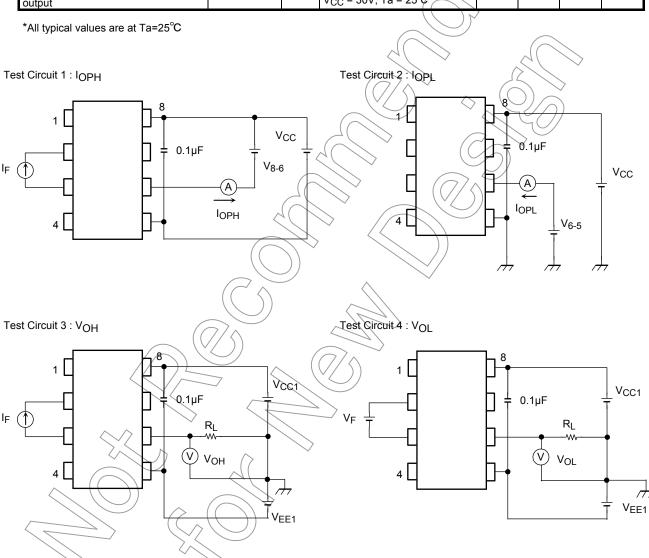
						77			
Characteristic		Symbol	Test Cir– cuit	Test Condition	Min:	Typ	Max.	Unit	
Input forward voltage		V _F	_	l _F = 10 mA , Ta = 25°C	(-)	1.6	1.8	V	
Temperature coefficient of forward voltage		ΔV _F / ΔTa	-(IF=10.mA) <u>/</u>	-2.0	_	mV / °C	
Input reverse current		I _R		V _R = 5V, Ta = 25°C) <u>}</u>	_	10	μA	
Input capacitance		C _T	1	V = 0 , f = 1MHz , Ta = 25°C	_	45	250	pF	
Output current	"H" level	I _{OPH}		$V_{CC}=30V$ $V_{8-6}=4V$	-0.1	-0.25	1	^	
	"L" level	lopL	2	(*1) $V_{6-5} = 2.5V$	0.1	0.2	l	A	
Output voltage	"H" level	Voh	3	$V_{CC1} = +15V, V_{EE1} = -15V$ $R_L = 200\Omega, I_F = 5mA$	11	13.2	ı	V	
	"L" level	V _{OL}	4	$V_{CC1} = +15V, V_{EE1} = -15V$ $R_L = 200\Omega, V_F = 0.8V$	_	-14.5	-12.5	V	
	"H" level	Іссн		V _{CC} = 30V, I _F = 10mA Ta = 25°C		7.5			
Supply current	Ÿ			V _{CC} = 30V, I _F = 10mA	_	_	11	mA	
Supply current	"L" level	IçqL		V _{CC} = 30V, I _F = 0mA Ta = 25°C	1	8	1	IIIA	
				V _{CC} = 30V, I _F = 0mA	_		11		
Threshould input current	"Output H"	IFLH	-	$V_{CC1} = +15V, V_{EE1} = -15V$ $R_L = 200\Omega, V_O > 0V$	_	1.2	5	mA	
Threshold input voltage	"Output H → L"	V _{FHL}	_	$V_{CC1} = +15V, V_{EE1} = -15V$ $R_L = 200\Omega, V_O < 0V$	0.8		_	V	
Supply voltage		V _{CC}	1		10	_	35	V	
Capacitance (input-output)		Cs	_	Vs = 0 , f = 1MHz Ta = 25℃	_	1.0	2.0	pF	
Resistance (input-output)		R _s	ı	Vs = 500V, Ta = 25°C R.H. ≤ 60%	1×10 ¹²	10 ¹⁴	-	Ω	

^{*} All typical values are at Ta=25°C

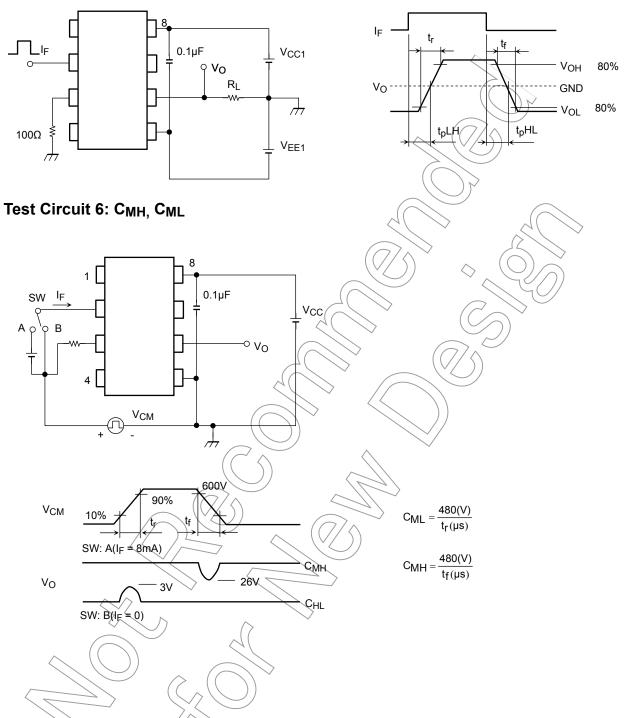
^{(*1):} Duration of I_O time ≤ 50µs

Switching Characteristics (Ta = $-20\sim70$ °C, unless otherwise specified)

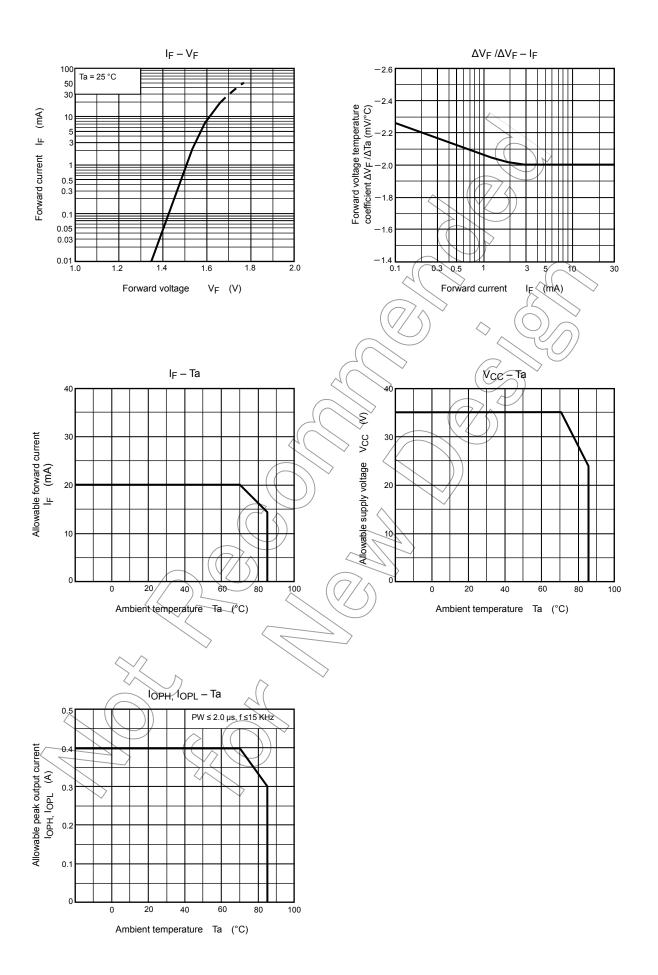
Characteristic		Symbol	Test Cir– cuit	Test Condition	Min.	Typ.*	Max.	Unit
Propagation	L→H	t _{pLH}	- - - 5	I _F = 8mA V _{CC1} = +15V, V _{EE1} = -15V	_	0.25	1.0	
delay time	H→L	t _{pHL}			_	0.25	1.0	
Output rise time		t _r		$R_L = 200 \Omega$	1	_	_	μs
Output fall time		t _f				\ <u>\</u>	_	
Common mode transient immunity at high level output		Смн	- 6	V _{CM} = 600V, I _F = 8mA, V _{CC} = 30V, Ta = 25°C	5000) <u> </u>	_	V / µs
Common mode transient immunity at low level output		C _{ML}		V _{CM} = 600V, I _F = 0mA, V _{CC} = 30V, Ta = 25°C	5000	_	_	V / µs



Test Circuit 5: tpLH, tpHL, tr, tf



 C_{ML} (C_{MH}) is the maximum rate of rise (fall) of the common mode voltage that can be sustained with the output voltage in the low (high) state.



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